Diode Semiconductor Device - Page 1 of 1



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Me	etal
	verall Length:
	300 inches
-	erminal Length:
	000 inches
	verall Diameter:
0. ⁻	107 inches
Mo	ounting Method:
Те	erminal
Fe	eatures Provided:
He	ermetically sealed case
Se	emiconductor Material:
Sil	licon
Vc	oltage Rating In Volts Per Characteristic:
30	0.0 reverse voltage, instantaneous
Сι	urrent Rating Per Characteristic:
30	0.00 milliamperes forward current, dc
Pc	ower Rating Per Characteristic:
0.6	6 watts total power dissipation
Ma	aximum Operating Tempurature Per Measurement Point:
20	0.0 degrees celsius ambient air
Pr	ecious Material And Location:
Te	erminal surface gold
Pr	ecious Material:
Go	bld
Те	erminal Type And Quantity:
2 ι	uninsulated wire lead
Sł	nelf Life:
N/	a
Ur	nit Of Measure:
De	emilitarization:
No	
Fii	ig:
A1	10a0